

Medium Power Phase Control Thyristors (Stud Version), 25 A



TO-208AA (TO-48)

FEATURES

- Improved glass passivation for high reliability and exceptional stability at high temperature
- High di/dt and dV/dt capabilities
- Standard package
- Low thermal resistance
- Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- Designed and qualified for industrial and consumer level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

PRODUCT SUMMARY	
Package	TO-208AA (TO-48)
Diode variation	Single SCR
$I_{T(AV)}$	25 A
V_{DRM}/V_{RRM}	100 V to 1200 V
V_{TM}	1.70 V
I_{GT}	60 mA
T_J	-65 °C to 125 °C

TYPICAL APPLICATIONS

- Medium power switching
- Phase control applications
- Can be supplied to meet stringent military, aerospace and other high reliability requirements

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$		25	A
	T_C	85	°C
$I_{T(RMS)}$		40	A
I_{TSM}	50 Hz	420	A
	60 Hz	440	
I^2t	50 Hz	867	A ² s
	60 Hz	790	
V_{DRM}/V_{RRM}		100 to 1200	V
t_q	Typical	110	μs
T_J		-65 to 125	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{DRM}/V_{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-25RIA	10	100	150	20
	20	200	300	10
	40	400	500	
	60	600	700	
	80	800	900	
	100	1000	1100	
	120	1200	1300	

Notes

⁽¹⁾ Units may be broken over non-repetitively in the off-state direction without damage, if di/dt does not exceed 20 A/μs

⁽²⁾ For voltage pulses with $t_p \leq 5$ ms



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current at case temperature	$I_{T(AV)}$	180° sinusoidal conduction		25	A
				85	°C
Maximum RMS on-state current	$I_{T(RMS)}$			40	A
Maximum peak, one-cycle non-repetitive surge current	I_{TSM}	t = 10 ms	No voltage reappplied	420	A
		t = 8.3 ms	No voltage reappplied	440	
		t = 10 ms	100 % V_{RRM} reappplied	350	
		t = 8.3 ms	100 % V_{RRM} reappplied	370	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reappplied	867	A^2s
		t = 8.3 ms	No voltage reappplied	790	
		t = 10 ms	100 % V_{RRM} reappplied	615	
		t = 8.3 ms	100 % V_{RRM} reappplied	560	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reappplied, $T_J = T_J$ maximum		8670	$A^2\sqrt{s}$
Low level value of threshold voltage	$V_{T(TO)1}$	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		0.99	V
High level value of threshold voltage	$V_{T(TO)2}$	$(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		1.40	
Low level value of on-state slope resistance	r_{t1}	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		10.1	mΩ
High level value of on-state slope resistance	r_{t2}	$(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		5.7	
Maximum on-state voltage	V_{TM}	$I_{pk} = 79$ A, $T_J = 25$ °C		1.70	V
Maximum holding current	I_H	$T_J = 25$ °C, anode supply 6 V, resistive load		130	mA
Latching current	I_L			200	

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum rate of rise of turned-on current	dI/dt	$T_J = T_J$ maximum, $V_{DM} =$ Rated V_{DRM} Gate pulse = 20 V, 15 Ω, $t_p = 6$ μs, $t_r = 0.1$ μs maximum $I_{TM} = (2 \times \text{rated } dI/dt)$ A		200	$A/\mu s$	
				$V_{DRM} \leq 600$ V		180
				$V_{DRM} \leq 800$ V		160
				$V_{DRM} \leq 1000$ V		150
Typical turn-on time	t_{gt}	$T_J = 25$ °C, at rated V_{DRM}/V_{RRM} , $T_J = 125$ °C		0.9	μs	
Typical reverse recovery time	t_{rr}	$T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200$ μs, $dI/dt = -10$ A/μs		4		
Typical turn-off time	t_q	$T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200$ μs, $V_R = 100$ V, $dI/dt = -10$ A/μs, $dV/dt = 20$ V/μs linear to 67 % V_{DRM} , gate bias 0 V to 100 W		110		

Note

- $t_q = 10$ μs up to 600 V, $t_q = 30$ μs up to 1600 V available on special request

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 100 % rated V_{DRM}		100	$V/\mu s$
		$T_J = T_J$ maximum linear to 67 % rated V_{DRM}		300 ⁽¹⁾	

Note

⁽¹⁾ Available with: $dV/dt = 1000$ V/μs, to complete code add S90 i.e. 25RIA120S90



TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum		8.0	W
Maximum average gate power	$P_{G(AV)}$			2.0	
Maximum peak positive gate current	I_{GM}	$T_J = T_J$ maximum		1.5	A
Maximum peak negative gate voltage	$-V_{GM}$	$T_J = T_J$ maximum		10	V
DC gate current required to trigger	I_{GT}	$T_J = -65\text{ }^\circ\text{C}$	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied	90	mA
		$T_J = 25\text{ }^\circ\text{C}$		60	
		$T_J = 125\text{ }^\circ\text{C}$		35	
DC gate voltage required to trigger	V_{GT}	$T_J = -65\text{ }^\circ\text{C}$		3.0	V
		$T_J = 25\text{ }^\circ\text{C}$		2.0	
		$T_J = 125\text{ }^\circ\text{C}$		1.0	
DC gate current not to trigger	I_{GD}	$T_J = T_J$ maximum, $V_{DRM} =$ Rated value		2.0	mA
DC gate voltage not to trigger	V_{GD}	$T_J = T_J$ maximum, $V_{DRM} =$ Rated value	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V_{DRM} anode to cathode applied	0.2	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum operating junction and storage temperature range	T_J, T_{Stg}			- 65 to 125	$^\circ\text{C}$
Maximum thermal resistance, junction to case	R_{thJC}	DC operation		0.75	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased		0.35	
Allowable mounting torque		Non-lubricated threads		$3.4 + 0 - 10\%$ (30)	N · m (lb · in)
		Lubricated threads		$23 + 0 - 10\%$ (20)	
Approximate weight				14	g
				0.49	oz.
Case style		See dimensions - link at the end of datasheet		TO-208AA (TO-48)	

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.17	0.13	$T_J = T_J$ maximum	K/W
120°	0.21	0.22		
90°	0.27	0.30		
60°	0.40	0.42		
30°	0.69	0.70		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



Fig. 1 - Current Ratings Characteristics

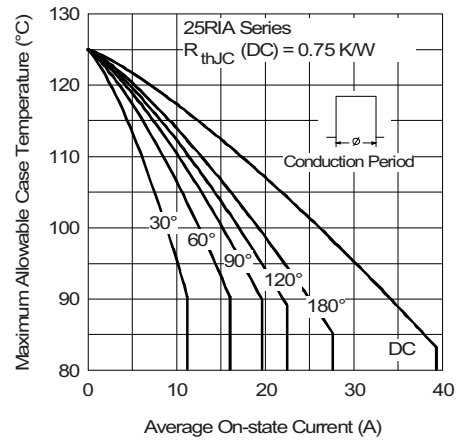


Fig. 1 - Current Ratings Characteristics

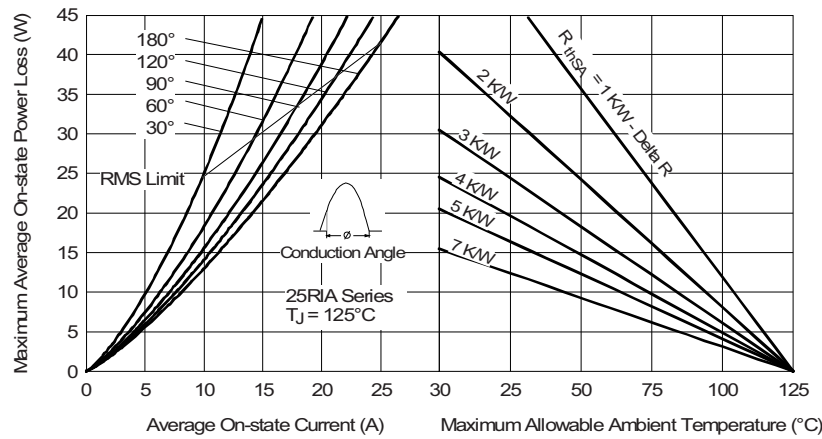


Fig. 2 - On-State Power Loss Characteristics



Fig. 3 - On-State Power Loss Characteristics



Fig. 4 - Maximum Non-Repetitive Surge Current



Fig. 5 - Maximum Non-Repetitive Surge Current



Fig. 6 - Forward Voltage Drop Characteristics



Fig. 7 - Thermal Impedance Z_{thJC} Characteristics

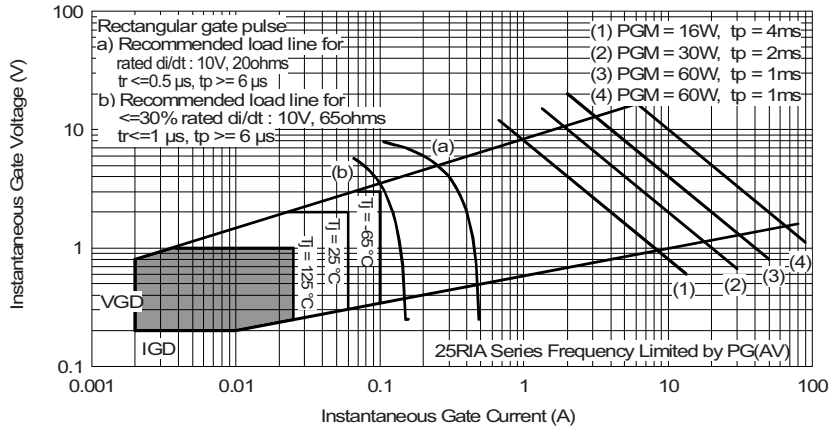


Fig. 8 - Gate Characteristics

ORDERING INFORMATION TABLE

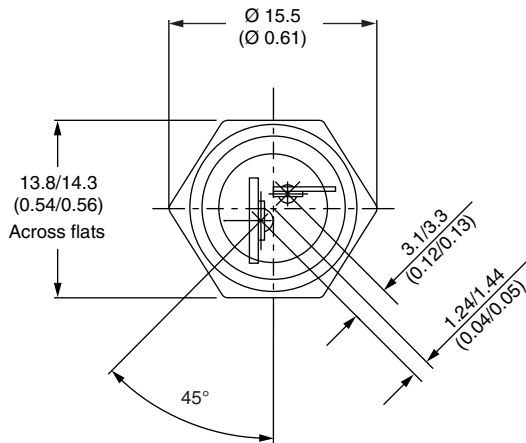
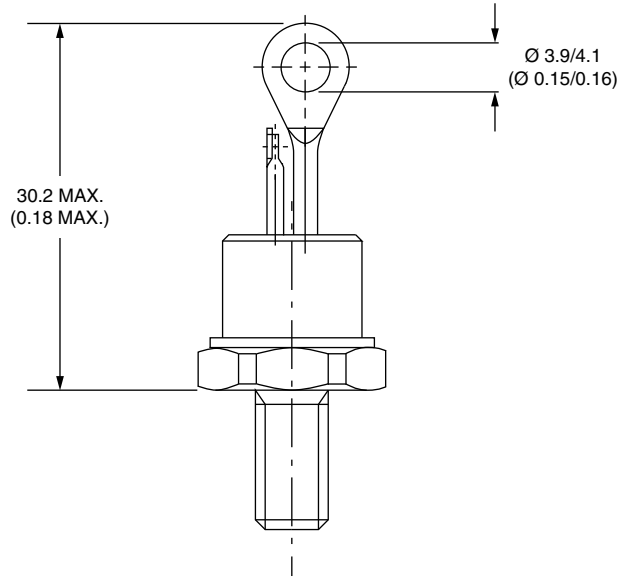
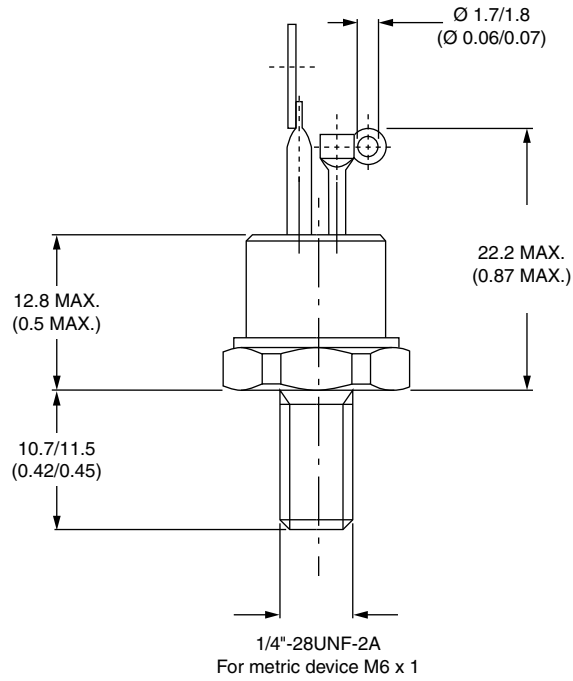
Device code	VS-	25	RIA	120	M	S90
	①	②	③	④	⑤	⑥

- 1** - Vishay Semiconductors product
- 2** - Current code
- 3** - Essential part number
- 4** - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- 5** - None = Stud base TO-208AA (TO-48) 1/4" 28UNF-2A
M = Stud base TO-208AA (TO-48) M6 x 1
- 6** - Critical dV/dt:
None = 300 V/μs (standard value)
S90 = 1000 V/μs (special selection)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95333

TO-208AA (TO-48)

DIMENSIONS in millimeters (inches)





Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «**JONHON**», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «**FORSTAR**».



JONHON

«**JONHON**» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«**FORSTAR**» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А